

## **AC/DC Converter**

# PWM Type DC/DC Converter IC Built-in a Switching MOSFET

## BM2P0161-Z BM2P0361-Z

#### **General Description**

The PWM type DC/DC converter for AC/DC provides an optimal system for all products that require an electrical outlet.

BM2P0161-Z and BM2P0361-Z support both isolated and non-isolated devices, enabling simpler design of various types of low power consumption electrical converters.

The built-in 730 V starter circuit contributes to low-power consumption.

Power supply can be designed flexibly by connecting current sensing resistor for the switching externally. Current is restricted in each cycle and excellent performance is demonstrated in bandwidth and transient response since current mode control is utilized. The switching frequency is 65 kHz. At light load, the switching frequency is reduced and high efficiency is achieved. A frequency hopping function that contributes to low EMI is also included on chip.

Design can be easily implemented because includes a 730 V switching MOSFET.

#### Feature

- PWM Current Mode Control
- Built-in Frequency Hopping Function
- Burst Operation When Load is Light
- Frequency Reduction Function
- Built-in 730 V Starter Circuit
- Built-in 730 V Switching MOSFET
- VCC Pin Under-Voltage Protection
- VCC Pin Over-Voltage Protection
- SOURCE Pin Open Protection
- SOURCE Pin Short Protection
- SOURCE Pin Leading Edge Blanking Function
- Per-Cycle Over-Current Protection Circuit
- Over Current Protection AC Voltage Compensation Circuit
- Soft Start
- Secondary Over-Current Protection Circuit

#### **Typical Application Circuit**

#### Key Specification

Operating Power Supply Voltage Range:

8.9 V to 26.0 V VCC: DRAIN: 730 V (Max) Circuit Current (ON)1: BM2P0161-Z: 0.90 mA (Typ) 0.65 mA (Typ) BM2P0361-Z: Circuit Current (ON)2: 0.30 mA (Typ) Oscillation Frequency1: 65 kHz (Typ) Operating Ambient Temperature: -40 °C to +105 °C MOSFET ON Resistance: BM2P0161-Z: 1.0 Ω (Typ) BM2P0361-Z: 3.0 Ω (Typ)

#### Package DIP7K

W (Typ) x D (Typ) x H (Max)

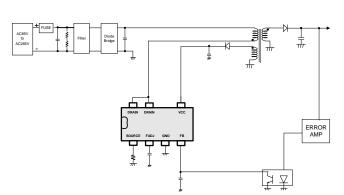
DIP7WF

9.27 mm x 6.35 mm x 8.63 mm Pitch 2.54 mm 9.35 mm x 6.35 mm x 8.10 mm Pitch 2.54 mm



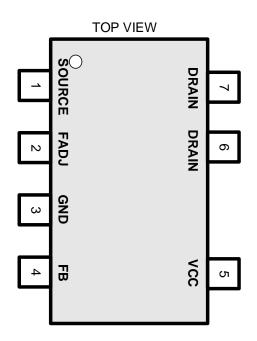
#### Application

For AC Adapters, TV and Household Appliances (Vacuum Cleaners, Humidifiers, Air Cleaners, Air Conditioners, IH Cooking Heaters, Rice Cookers, etc.)



OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays.

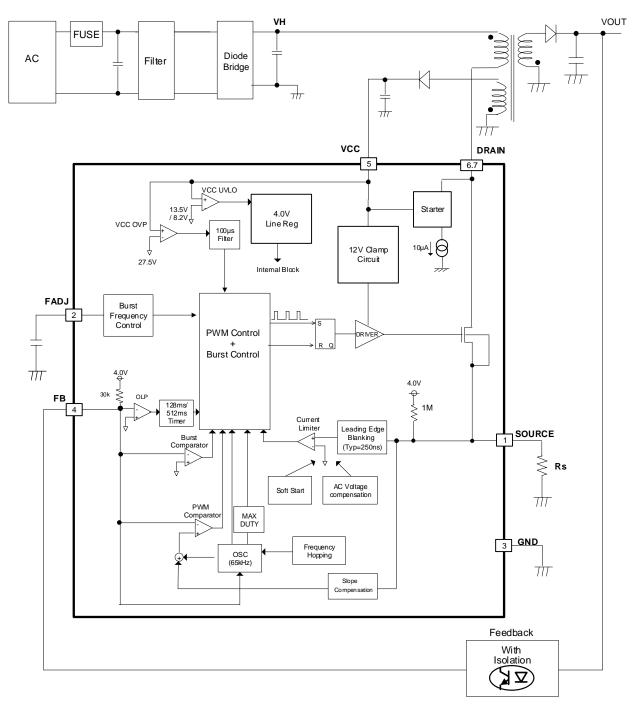
## **Pin Configuration**



## **Pin Description**

Pin No.	Pin Name	I/O	Function	ESD Diode		
FILLINO.	Fininame	1/0	Function	VCC	GND	
1	SOURCE	I/O	MOSFET SOURCE pin	0	0	
2	FADJ	I	Burst frequency setting pin	0	0	
3	GND	I/O	GND pin	0	-	
4	FB	I	Feedback signal input pin	0	0	
5	VCC	I	Power supply input pin	-	0	
6	DRAIN	I/O	MOSFET DRAIN pin	-	-	
7	DRAIN	I/O	MOSFET DRAIN pin	-	-	

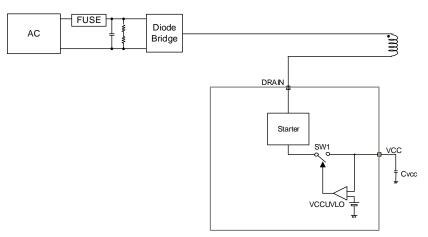
## **Block Diagram**

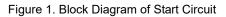


## **Description of Blocks**

#### 1. Start Circuit (DRAIN: Pin 6,7)

These ICs have a built-in start circuit. It enables low standby mode electricity and high speed start. After start up, consumption power is determined by idling current I<sub>START3</sub> only. Reference values of starting time are shown in Figure 3. When  $C_{VCC} = 10 \ \mu\text{F}$  it can start in less than 0.1 s.





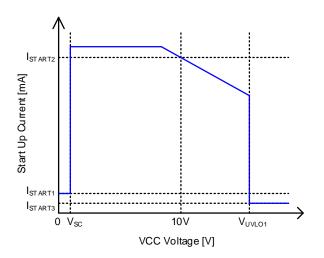


Figure 2. Start Up Current vs VCC Voltage

\* Start current flows from the DRAIN pin.

e.g.) Consumption power of start circuit only when Vac = 100 V

## $PVH = 100V \times \sqrt{2} \times 10\mu A = 1.41mW$

e.g.) Consumption power of start circuit only when Vac = 240 V

$$PVH = 240V \times \sqrt{2} \times 10\mu A = 3.39mW$$

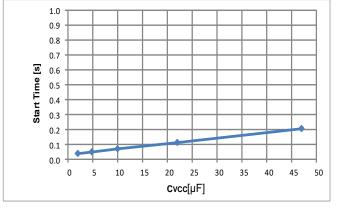


Figure 3. Start Time vs Cvcc

## **Description of Blocks - continued**

#### 2. Start Sequences

Start sequences are shown in Figure 4. See the sections below for detailed descriptions.

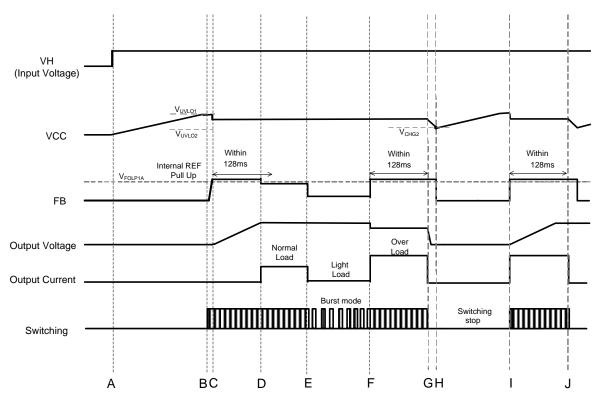


Figure 4. Start Sequences Timing Chart

- A: Input voltage VH is applied.
- B: This IC starts operating when VCC > V<sub>UVLO1</sub>. Switching function starts when other protection functions are judged as normal. Until the secondary output voltage becomes constant value or more from startup, the VCC pin consumption current causes the VCC voltage to drop. As a result, IC should be set to VCC > V<sub>UVLO2</sub> until switching starts.
- C: With the soft start function, over current limit value is restricted to prevent any excessive rise in voltage or current.
- D: When the switching operation starts, VOUT rises.
- After a switching operating start, set the rated voltage within the tFOLP1 period.
- E: When there is a light load, it makes FB voltage < VBST. Burst operation is used to keep power consumption down.
- F: When the FB pin voltage >  $V_{FOLP1A}$ , it overloads.
- G: When the FB pin voltage > V<sub>FOLP1A</sub> keeps above t<sub>FOLP1</sub>, overcurrent protection is caused between t<sub>FOLP2</sub> period, and switching stops. If the FB pin voltage < V<sub>FOLP1B</sub>, the ICs internal timer t<sub>FOLP1</sub> is reset.
- H: If the VCC voltage <  $V_{CHG2}$ , recharge operation raises the VCC voltage.
- I: Same as F.
- J: Same as G.

## **Description of Blocks – continued**

#### 3. VCC Pin Protection Function

These ICs have a built-in VCC UVLO (Under Voltage Lockout), VCC OVP (Over Voltage Protection), and a VCC recharge function that operates in case of a drop in VCC voltage.

VCC charge function stabilizes the secondary output voltage, charged from high voltage lines by the start circuit when VCC voltage drops.

#### (1) VCC UVLO / VCC OVP Function

VCC UVLO and VCC OVP are the self-recovery type comparator having voltage hysteresis.

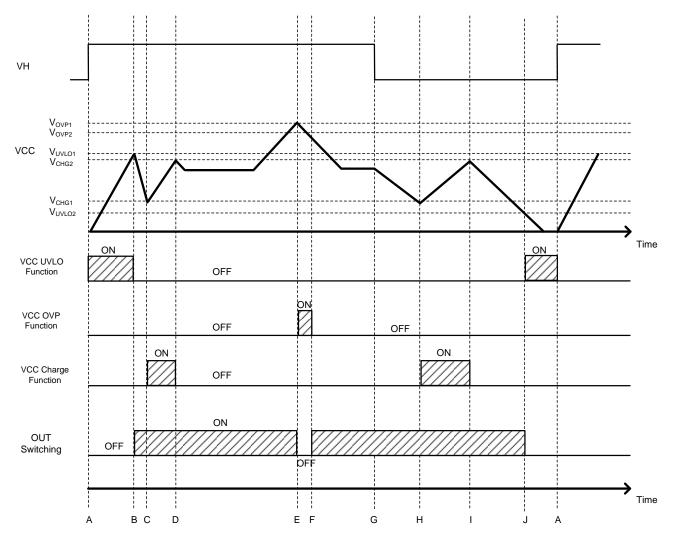


Figure 5. VCC UVLO / OVP Timing Chart

- A: DRAIN voltage inputs, the VCC pin voltage starts rising.
- B: VCC > VUVLO1, VCC UVLO function is released and DC/DC operation starts.
- C: VCC <  $V_{CHG1}$ , VCC charge function operates and the VCC voltage rises.
- D: VCC >  $V_{CHG2}$ , VCC charge function stops.
- E: VCC > V<sub>OVP1</sub>, t<sub>LATCH</sub> (100 μs Typ) continues, switching is stopped by the VCC OVP function.
- F: VCC <  $V_{OVP2}$ , DC/DC operation restarts.
- G: VH is OPEN. VCC Voltage falls.
- H: Same as C.
- I: Same as D.
- J: VCC < V<sub>UVLO2</sub>, VCC UVLO function is detected and DC/DC operation stops.

#### 3. VCC Pin Protection Function – continued

#### (2) VCC Charge Function

These ICs have the recharge function.

IC starts when the VCC pin voltage > V<sub>UVLO1</sub>. When VCC voltage becomes VCC < V<sub>CHG1</sub> after IC started, VCC recharge function works. At that time the VCC pin is charged from the DRAIN pin through the start circuit.

Through this operation, these series prevent failure of VCC startup.

When the VCC pin voltage rises until VCC > V<sub>CHG2</sub>, it finishes recharge. The operation is shown in Figure 6.

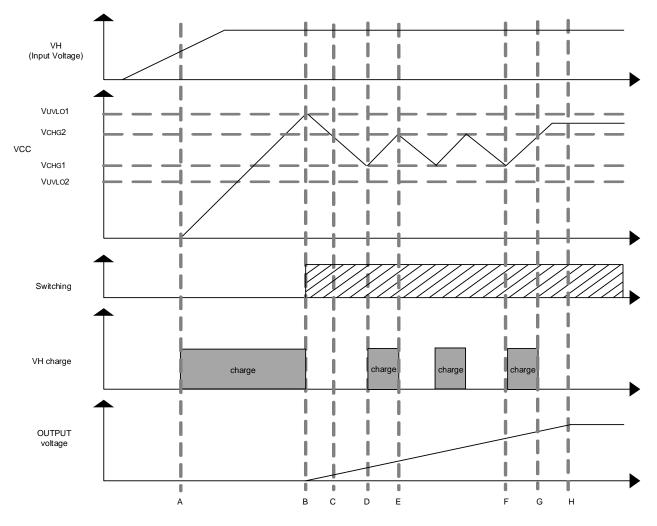


Figure 6. VCC Pin Charge Operation

- A: The DRAIN pin voltage rises, charges the VCC pin through the VCC charge function.
- B: VCC > V<sub>UVLO1</sub>, VCC UVLO function releases, VCC charge function stops, DC/DC operation starts.
- C: Because output voltage is low, the VCC voltage drops at the start time.
- D: VCC < V<sub>CHG1</sub>, VCC recharge function operates, and the VCC pin voltage rise.
- E: VCC >  $V_{CHG2}$ , VCC recharge function stops.
- F: VCC < V<sub>CHG1</sub>, VCC recharge function operates, and the VCC pin voltage rise.
- G: VCC > V<sub>CHG2</sub>, VCC recharge function stops.
- H: After the output voltage is finished rising, VCC is charged by the auxiliary winding, and the VCC pin stabilizes.

## **Description of Blocks – continued**

#### 4. DC/DC Driver

These ICs have a current mode PWM control. An internal oscillator sets a fixed switching frequency (65 kHz Typ). It has a switching frequency hopping function, which causes the switching frequency to fluctuate as shown in Figure 7 below.

The fluctuation cycle is 125 Hz.(Typ)

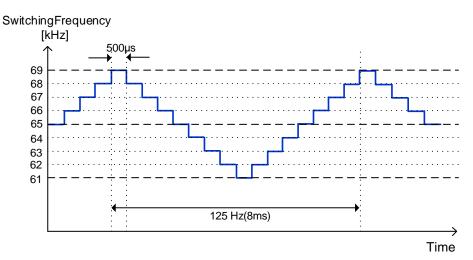


Figure 7. Frequency Hopping Function

Maximum duty cycle is fixed at 75 % and minimum ON time is fixed at 400 ns.

In current mode control, sub-harmonic oscillation may occur when the duty cycle exceeds 50 %.

As a countermeasure, this IC has built-in slope compensation circuits.

These ICs have built-in burst mode and frequency reduction circuits to achieve lower power consumption when the load is light.

The FB pin is pulled up to an internal power supply by R<sub>FB</sub>.

The FB pin voltage is changed by secondary output voltage (secondary load power).

Monitor the FB pin voltage and change a switching operation state.

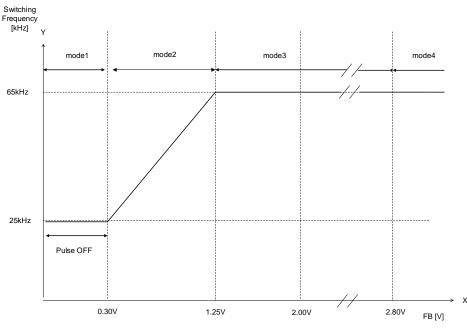
Figure 8 shows the FB voltage, and the DC/DC switching frequency operation.

mode1: Burst operation.

mode2: Frequency reduction operation. (Max frequency is reduced)

mode3: Fixed frequency operation. (Operates at max frequency)

mode4: Overload operation. (Stops the pulse operation, sampling operation)



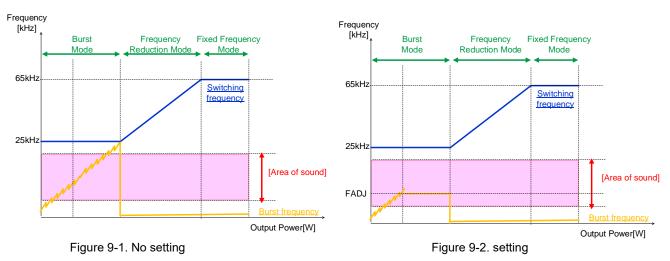


#### 4. DC/DC Driver – continued

**Burst Frequency Setting** 

The frequency can be fixed by adding capacitance to the FADJ pin. This can reduce the burst sounds. Set the capacitor connected to FADJ to 2200 pF or less.

The characteristics of the capacitor C<sub>FADJ</sub> connected to the FADJ pin and frequency f<sub>BST</sub> is shown in the Figure 10.



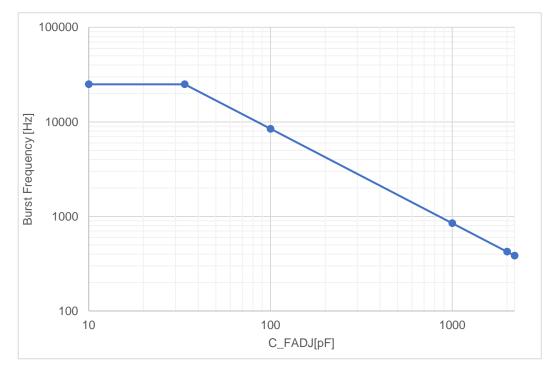


Figure 10. fBST vs CFADJ

## **Description of Blocks – continued**

#### 5. Over Current Limiter

These ICs have a built-in over current limiter per switching cycle.

If the SOURCE pin exceeds a certain voltage, switching stops. It also has a built-in AC voltage compensation function. This function is a compensation function to increase the over current limiter level by AC voltage compensation function time.

Shown in Figure 11, 12, 13.

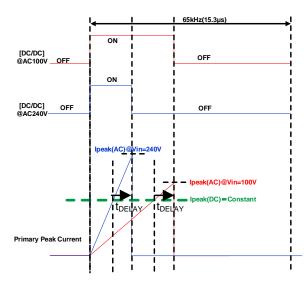


Figure 11. No AC Voltage Compensation Function

Primary peak current is calculated using the formula below.

$$Ipeak = \frac{V_{SOURCE}}{Rs} + \frac{Vdc}{Lp} \times tdelay$$

Where:

 $V_{SOURCE}$  is the over current limiter voltage (internal). Rs is the current detection resistance. Vdc is the input DC voltage. Lp is the primary inductance. tdelay is the delay time after detection of over current limiter.

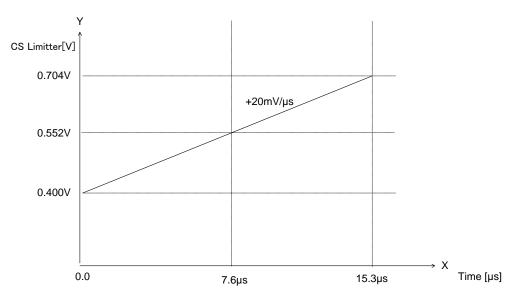


Figure 13. Over Current Limiter Voltage

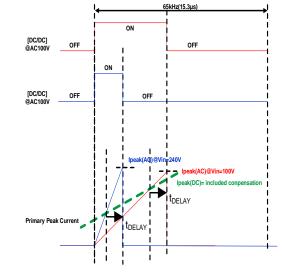


Figure 12. Built-in AC Compensation Voltage

## **Description of Blocks – continued**

#### 6. L. E. B. Blanking Period

When the MOSFET driver is turned ON, surge current flows through each capacitor component and drive current is generated. Therefore, when the SOURCE pin voltage rises temporarily, detection errors may occur in the over current limiter circuit. To prevent detection errors, DRAIN is switched from high to low and the SOURCE signal is masked for 250 ns by the on-chip LEB (Leading Edge Blanking) function.

#### 7. SOURCE Pin Short Protection Function

When the SOURCE pin is shorted, excessive heat may destroy the IC. To prevent it from being damaged, these ICs have a built-in short protection function.

#### 8. SOURCE Pin Open Protection

When the SOURCE pin becomes OPEN, excessive heat by noise may destroy the IC. To prevent it from being damaged, these ICs have a built-in OPEN protection circuit (auto recovery protection).

#### 9. Output Overload Protection Function (FB OLP Comparator)

The output overload protection function monitors the secondary output load status at the FB pin and stops switching whenever overload occurs. When there is an overload, the output voltage is reduced and current no longer flows to the photo coupler, so the FB pin voltage rises.

When the FB pin voltage >  $V_{FOLP1A}$  continuously for the period  $t_{FOLP1}$ , it is judged as an overload and switching stops. When the FB pin >  $V_{FOLP1A}$ , the voltage goes lower than  $V_{FOLP1B}$  during the period  $t_{FOLP1}$ , the overload protection timer is reset. The switching operation is performed during this period  $t_{FOLP1}$ .

At startup, the FB voltage is pulled up to the IC's internal voltage, so operation starts at a voltage of  $V_{FOLP1A}$  or above. Therefore, at startup please set startup time within  $t_{FOLP1}$  so that the FB voltage becomes  $V_{FOLP1B}$  or less. Recovery is after the period  $t_{FOLP2}$ , from the detection of FBOLP.

#### Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit	Conditions
Maximum Applied Voltage 1	VMAX1	-0.3 to +32.0	V	VCC
Maximum Applied Voltage 2	V <sub>MAX2</sub>	-0.3 to +6.5	V	SOURCE, FB, FADJ
	N/	650	V	DRAIN
Maximum Applied Voltage 3	V <sub>MAX3</sub>	730	V	DRAIN (tpulse < 10 µs) (Note 1)
Drain Current Pulse	IDP	12	А	Pw = 10 μs, Duty cycle = 1 % (BM2P0161-Ζ)
Drain Current Pulse	IDP	4	А	P <sub>w</sub> = 10 µs, Duty cycle = 1 % (BM2P0361-Z)
Power Dissipation	Pd	1.00	W	(Note 2)
Maximum Junction Temperature	Tjmax	150	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with power dissipation taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.
(Note 1) Duty is less than 1 %.

(Note 2) When mounted (on 74.2 mm x 74.2 mm, 1.6 mm thick, glass epoxy on single-layer substrate). Reduce to 8 mW/°C when Ta = 25 °C or above.

#### Thermal Loss

The thermal design should set operation for the following conditions.

- 1. The ambient temperature Ta must be 105 °C or less.
- 2. The IC's loss must be within the power dissipation Pd.

#### The thermal abatement characteristics are as follows.

(PCB: 74.2 mm x 74.2mm x 1.6 mm, mounted on glass epoxy on single-layer substrate)

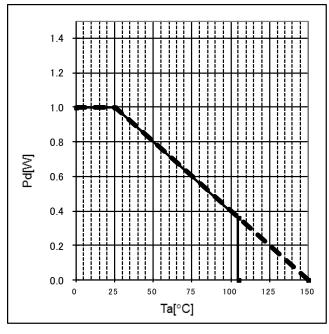


Figure 14. DIP7K Thermal Abatement Characteristics

#### **Recommended Operating Conditions**

Parameter	Sympol	Rating			Linit	Canditiana
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Power Supply Voltage Range 1	VCC	8.9	-	26.0	V	VCC pin voltage
	\/	-	-	650	V	DRAIN pin voltage
Power Supply Voltage Range 2	Vdrain	-	-	730	V	DRAIN (tpulse < 10 µs) <sup>(Note 1)</sup>
Operating Temperature	Topr	-40	-	+105	°C	

(Note 1) Duty is less than 1 %

## Electrical Characteristics (unless otherwise noted, Ta = 25 °C, VCC = 15 V)

Parameter	Symbol		Rating		Unit	Conditions
Faranielei	Symbol	Symbol Min Typ Max		Unit	Conditions	
[MOSFET Block]						
		650	-	-	V	$I_{D}$ = 1 mA / $V_{GS}$ = 0 V
Between Drain and Source Voltage	V <sub>(BR)DDS</sub>	730	-	-	V	$I_D$ = 1 mA, $V_{GS}$ = 0 V tpulse < 10 µs
Drain Leak Current	IDSS	-	-	100	μA	$V_{DS} = 650 \text{ V} / V_{GS} = 0 \text{ V}$
On Resistance	Rds(on)	-	1.0	1.4	Ω	I <sub>D</sub> = 0.25 A / V <sub>GS</sub> = 10 V (BM2P0161-Z)
On Resistance	Rds(on)	-	3.0	3.6	Ω	I <sub>D</sub> = 0.25 A / V <sub>GS</sub> = 10 V (BM2P0361-Z)

## **Electrical Characteristics – continued**

Parameter	Symbol	Min	pecification		Unit	Conditions
[Circuit Current]		IVIITI	Тур	Max		
Circuit Current (ON) 1	Ion1	-	900	1450	μA	V <sub>FB</sub> = 2.0 V (at pulse operation) (BM2P0161-Z)
Circuit Current (ON) 1	I <sub>ON1</sub>	-	650	1050	μA	V <sub>FB</sub> = 2.0 V (at pulse operation) (BM2P0361-Z)
Circuit Current (ON) 2	I <sub>ON2</sub>	150	300	450	μA	V <sub>FB</sub> = 0.3 V
[VCC Protection Function]			1			
VCC UVLO Voltage 1	V <sub>UVL01</sub>	12.50	13.50	14.50	V	VCC rise
VCC UVLO Voltage 2	VUVLO2	7.50	8.20	8.90	V	VCC fall
VCC UVLO Hysteresis	V <sub>UVLO3</sub>	-	5.30	-	V	VUVLO3 = VUVLO1-VUVLO2
VCC OVP Voltage 1	Vovp1	26.0	27.5	29.0	V	VCC rise
VCC OVP Voltage 2	Vovp2	22.0	23.5	25.0	V	VCC fall
VCC OVP Hysteresis	Vovp3	-	4.0	-	V	VOVP3 = VOVP1-VOVP2
VCC Recharge Start Voltage	V <sub>CHG1</sub>	7.70	8.70	9.70	V	
VCC Recharge Stop Voltage	V <sub>CHG2</sub>	12.00	13.00	14.00	V	
Latch Mask Time	<b>t</b> LATCH	50	100	150	μs	
Thermal Shutdown Temperature 1	T <sub>SD1</sub>	120	145	170	°C	Control IC, temperature rise
Thermal Shutdown Temperature 2	T <sub>SD2</sub>	90	115	140	°C	Control IC, temperature fall
[PWM Type DC/DC Driver Block]	ll.	4	1	l.	1	
Oscillation Frequency 1	fsw1	60	65	70	kHz	V <sub>FB</sub> = 2.00 V
Oscillation Frequency 2	f <sub>SW2</sub>	20	25	30	kHz	V <sub>FB</sub> = 0.30 V
Frequency Hopping Width 1	f <sub>DEL1</sub>	-	4.0	-	kHz	V <sub>FB</sub> = 2.0 V
Hopping Fluctuation Frequency	fсн	75	125	175	Hz	
FADJ Source Current	I <sub>BST</sub>	0.80	1.00	1.20	μA	FADJ = 0.0 V
FADJ Comparator Voltage	VBST	1.13	1.20	1.27	V	
FADJ Max Burst Frequency	f <sub>BST</sub>	-	0.833	-	kHz	C <sub>FADJ</sub> = 1000 pF
Soft Start Time 1	tss1	0.30	0.50	0.70	ms	
Soft Start Time 2	t <sub>SS2</sub>	0.60	1.00	1.40	ms	
Soft Start Time 3	tss3	1.20	2.00	2.80	ms	
Soft Start Time 4	tss4	4.80	8.00	11.20	ms	
Maximum Duty	D <sub>MAX</sub>	68.0	75.0	82.0	%	
Minimum ON Time	t <sub>MIN</sub>	150	400	650	ns	
FB Pin Pull-Up Resistance	Rfb	23	30	37	kΩ	
ΔFB / ΔSOURCE Gain	Gain	3.00	4.00	7.00	V/V	
FB Burst Voltage 1	V <sub>BST1</sub>	0.220	0.280	0.340	V	FB fall
FB Burst Voltage 2	VBST2	0.260	0.320	0.380	V	FB rise
FB Burst Hysteresis	V <sub>BST3</sub>	-	0.040	-	V	V <sub>BST3</sub> = V <sub>BST2</sub> -V <sub>BST1</sub>
FB Voltage of Starting Frequency Reduction	Vdlt	1.100	1.250	1.400	V	
FB OLP Voltage 1a	VFOLP1A	2.60	2.80	3.00	V	Overload is detected (FB rise
FB OLP Voltage 1b	V <sub>FOLP1B</sub>	2.40	2.60	2.80	V	Overload is detected (FB fall)
FB OLP ON Detect Timer	t <sub>FOLP1</sub>	80	128	176	ms	
FB OLP OFF Timer	t <sub>FOLP2</sub>	332	512	692	ms	

## **Electrical Characteristics – continued**

Parameter	Symbol	Specifications			Unit	Conditions	
Parameter	Symbol	Min	Тур	Max	Unit	Conditions	
[Over Current Detection Block]							
Over-Current Detection Voltage	VSOURCE	0.375	0.400	0.425	V	t <sub>on</sub> = 0 μs	
Over-Current Detection Voltage SS1	VSOURCE_SS1	0.050	0.100	0.150	V	0 ms to t <sub>SS1</sub> ms	
Over-Current Detection Voltage SS2	VSOURCE_SS2	0.080	0.150	0.220	V	tss1 ms to tss2 ms	
Over-Current Detection Voltage SS3	VSOURCE_SS3	0.130	0.200	0.270	V	tss2 ms to tss3 ms	
Over-Current Detection Voltage SS4	V <sub>SOURCE_SS4</sub>	0.230	0.300	0.370	V	t <sub>SS3</sub> ms to t <sub>SS4</sub> ms	
Leading Edge Blanking Time	t <sub>LEB</sub>	120	250	380	ns	(Note 2)	
Over Current Detection AC Voltage Compensation Factor	KSOURCE	12	20	28	mV/µs		
SOURCE Pin Short Protection Voltage	VSOURCESHT	0.020	0.050	0.080	V		
SOURCE Pin Short Protection Time	<b>t</b> SOURCESHT	1.80	3.00	4.20	μs		
[Circuit Current]						•	
Start Current 1	I <sub>START1</sub>	0.100	0.500	1.000	mA	VCC = 0 V	
Start Current 2	ISTART2	1.000	3.000	6.000	mA	VCC = 10 V	
OFF Current	Istart3	-	10	20	μA	Inflow current from the DRAIN pin after UVLO is released and when MOSFET is OFF	
Start Current Switching Voltage	Vsc	0.800	1.500	2.100	V		

(Note 2) Not 100 % tested.

## Application Examples

Show a flyback circuitry example in Figure 15. Be careful with the DRAIN voltage because high voltage is produced by ringing in turn OFF. With this IC, it become able to work to 730 V.

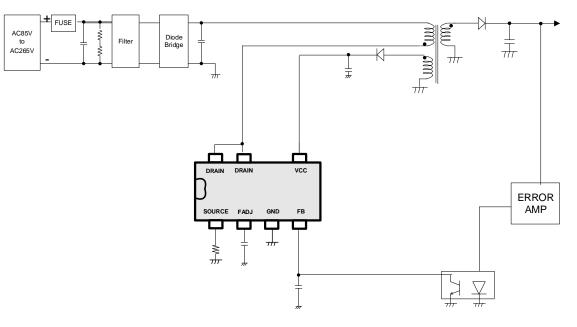


Figure 15. Flyback Application Ciucit

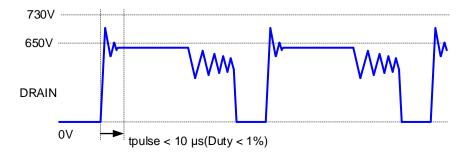


Figure 16. Drain Pin Ringing Waveform

## I/O Equivalence Circuit

1	SOURCE	2	FADJ	3	GND	4	FB
SOURCE						FB T	R <sub>FB</sub>
5	VCC	-	-	6	DRAIN	7	DRAIN
vcc	T m		-	Internal Circuit Intern		Internal Circuit Intern	

#### **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

#### 6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 7. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Interpin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### 10. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

#### **Operational Notes – continued**

#### 11. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

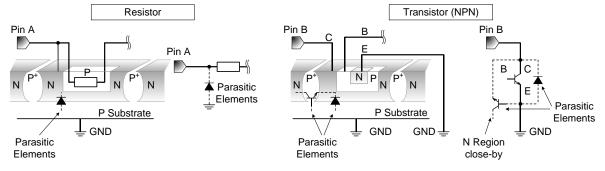


Figure 16. Example of monolithic IC structure

#### 12. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

#### 13. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and the maximum junction temperature rating are all within the Area of Safe Operation (ASO).

#### 14. Thermal Shutdown Circuit (TSD)

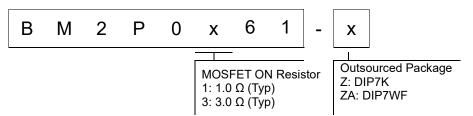
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

#### 15. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

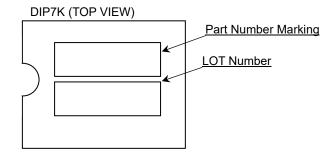
## Ordering Information

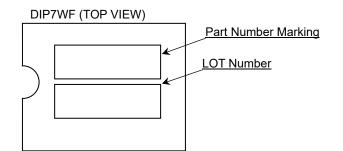


## Lineup

Orderable Part Number	MOSFET ON Resistor	MOSFET Withstand Voltage (V)	Package	Part Number Marking
BM2P0161-Z	1.0 Ω (Typ)	730	DIP7K	BM2P0161
BM2P0361-Z	3.0 Ω (Typ)	730		BM2P0361
BM2P0161-ZA	1.0 Ω (Typ)	730	DIP7WF	BM2P0161
BM2P0361-ZA	3.0 Ω (Typ)	730	DIF/WF	BM2P0361

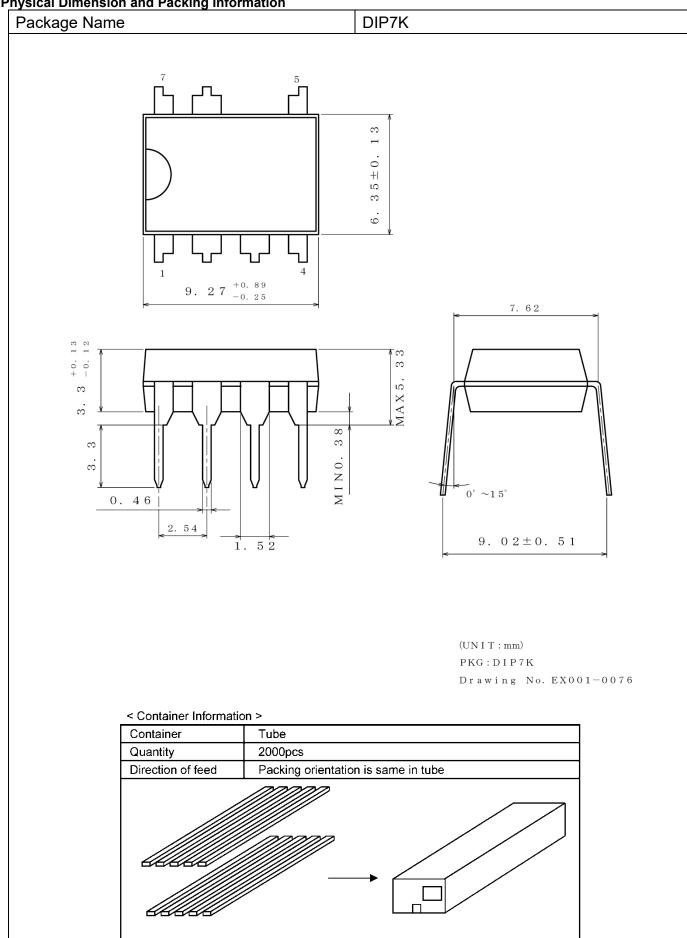
## Making Diagram



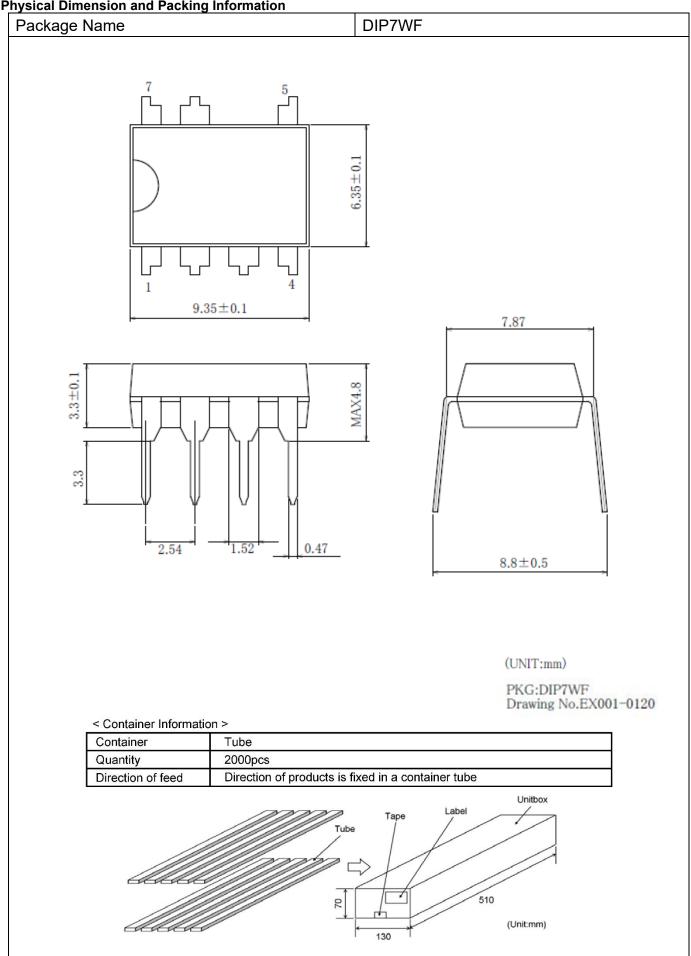


## Datasheet









## **Revision History**

Date	Revision	Changes
15.May.2018	001	New Release
20.Mar.2019	002	P1 Modify the size of package
13.Dec.2019	003	Revise Japanese datasheet
05.Jun.2020	004	Modify P14 Figure15
07.Dec.2020	005	P11 Change the Absolute Maximum Ratings P15 Addition of the Application Circuit
26.Oct.2021	006	P1 Add the package variation P19 Add the package variation P21 Add the physical dimension
08.Apr.2022	007	P9 Add the FADJ recommended conditions

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(Note1) Medical Equipment Classification of the Specific Applications
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JAPAN	USA	EU	CHINA	
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CLASSⅣ	CLASSII	CLASSⅢ	CLASSⅢ	

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  - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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